NSN 5980-01-097-3037

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View Online at https://aerobasegroup.com/nsn/5980-01-097-3037

Inclosure Material:
Plastic and metal
Overall Length:
0.520 inches
Overall Diameter:
0.388 inches
Mounting Facility Quantity:
1
Internal Configuration:
Point contact
Internal Junction Configuration:
Pn
Mounting Method:
Threaded stud
Features Provided:
Hermetically sealed case and mounting hardware
Thread Size:
0.312 inches
Semiconductor Material:
Gallium arsenide phosphide
Voltage Rating In Volts Per Characteristic:
5.0 breakdown voltage, dc
Current Rating Per Characteristic:
30.00 milliamperes source cutoff current preset
Power Rating Per Characteristic:
120.0 milliwatts small-signal input power, common-collector
Color Tone Produced Per Source:
Green semiconductor
Luminous Intensity:
4.0 millicandela
Maximum Operating Tempurature Per Measurement Point:
100.0 degrees celsius ambient air
Test Data Document:
81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Thread Series Designator:
Unf
Terminal Type And Quantity:
2 pin
Specification Data:
81349-mil-s-19500/521 government specification

N/a

Shelf Life:

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Demilitarization:

Yes - demil/mli

Fiig:

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